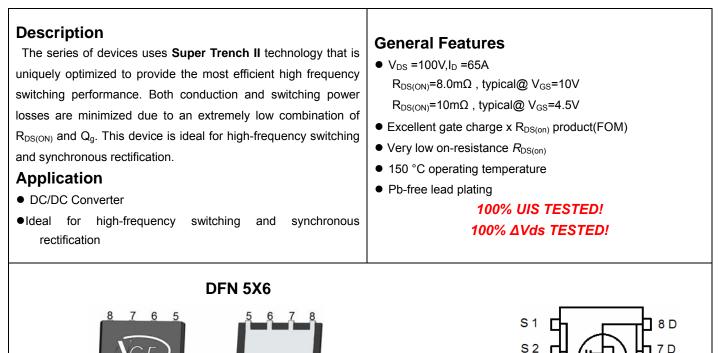


NCE N-Channel Super Trench II Power MOSFET



Package Marking and Ordering Information

Top View

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P090N10AGU	NCEP090N10AGU	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Bottom View

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	Ι _D	65	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	47	А
Pulsed Drain Current	I _{DM}	260	А
Maximum Power Dissipation	PD	85	W
Derating factor		0.68	W/℃
Single pulse avalanche energy (Note 4)	E _{AS}	288	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{eJC}	1.47	°C <i>I</i> W	
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S 3

G 4

6 D

5 D

Schematic Diagram



Electrical Characteristics (T_c=25[°]Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·		·	•		•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)	· ·		·	•		•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1.1	1.7	2.5	V
Drain-Source On-State Resistance		V _{GS} =10V, I _D =32.5A	-	8.0	9.0	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =32.5A	-	10.0	11.5	
Forward Transconductance	g fs	V _{DS} =5V,I _D =32.5A		50	-	S
Dynamic Characteristics (Note3)						
Input Capacitance	C _{lss}	V _{DS} =50V,V _{GS} =0V, F=1.0MHz	-	2600	-	pF
Output Capacitance	C _{oss}		-	230	-	pF
Reverse Transfer Capacitance	C _{rss}		-	27	-	pF
Switching Characteristics (Note 3)	· ·		·	•		•
Turn-on Delay Time	t _{d(on)}		-	13	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D =32.5A V _{GS} =10V,R _G =1.6Ω	-	10	-	nS
Turn-Off Delay Time	t _{d(off)}		-	30	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg		-	54	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =50V,I _D =32.5A,	-	10	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	14	-	nC
Drain-Source Diode Characteristics	· ·		·	•		
Diode Forward Voltage (Note 2)	V _{SD}	V _{GS} =0V,I _S =32.5A	-	-	1.2	V
Diode Forward Current	Is		-	-	65	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = 32.5A$	-	55	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	98	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

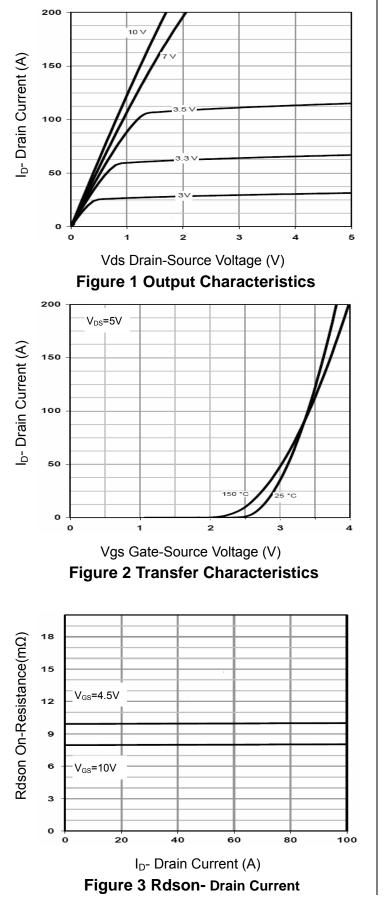
2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

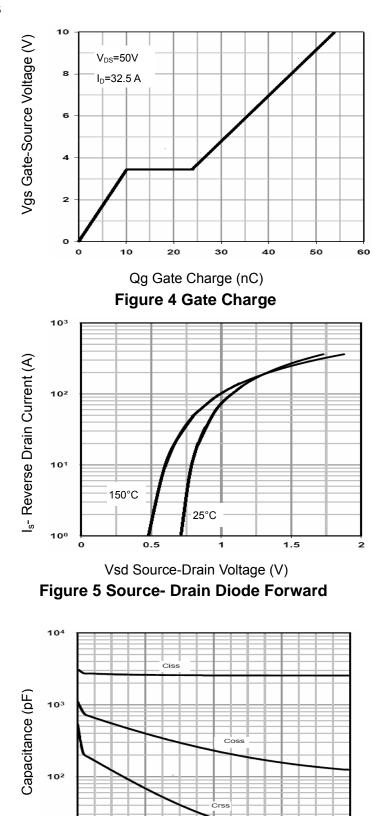
3. Guaranteed by design, not subject to production

4. EAS condition : Tj=25 $^\circ C$,V_DD=50V,V_G=10V,L=0.25mH,Rg=25 Ω



Typical Electrical and Thermal Characteristics





10¹

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25

50

Vds Drain-Source Voltage (V)

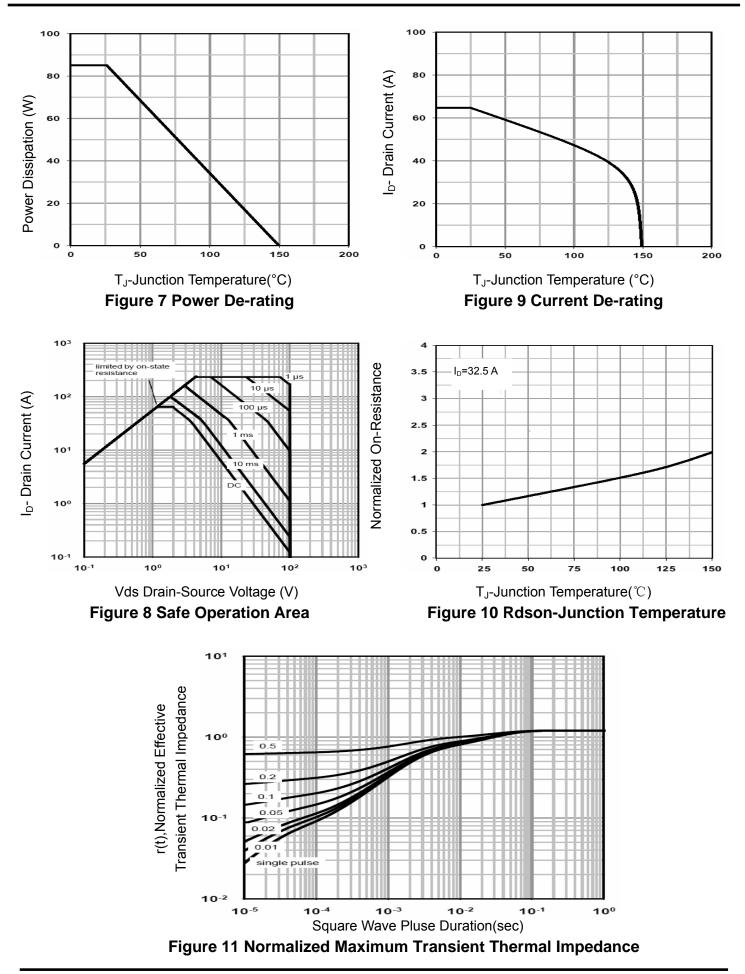
Figure 6 Capacitance vs Vds

100

75

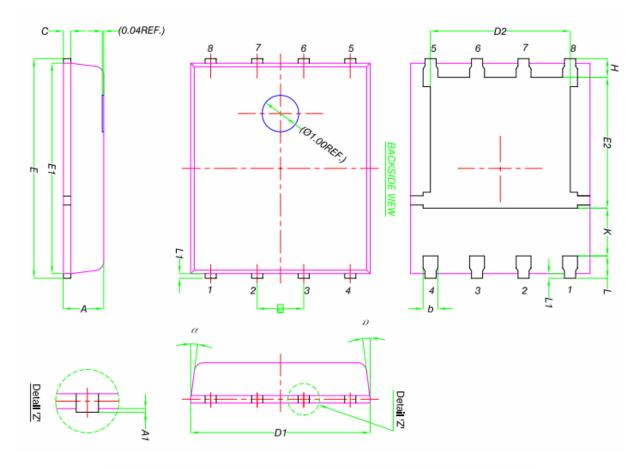


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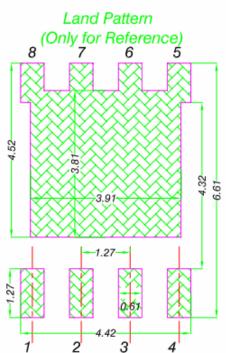




DFN5X6-8L Package Information



	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
А	0.90	1.00	1.10	
A1	0	-	0.05	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
E	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
е	1.27 BSC			
Н	0.41	0.51	0.61	
к	1.10	-	-	
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
α	0°	-	12°	





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